



Geant4 Tutorial Course

Jefferson Lab, Newport News, VA, USA August 18-22 2025

Electromagnetic Physics I

Maurizio Ungaro
Jefferson Lab

Content from Mihaly Novak (CERN, EP-SFT) and Vladimir Ivantchenko (Tomsk State University)

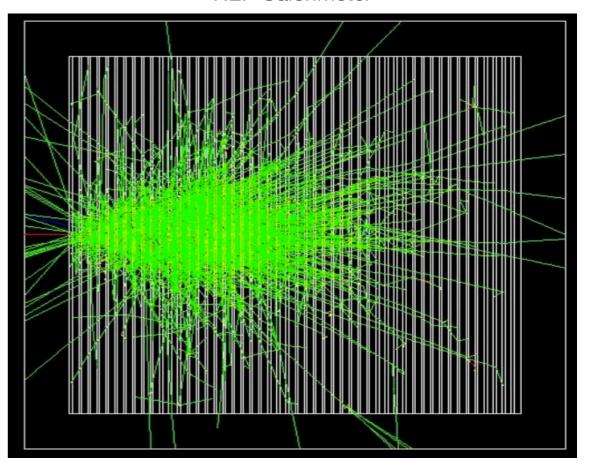


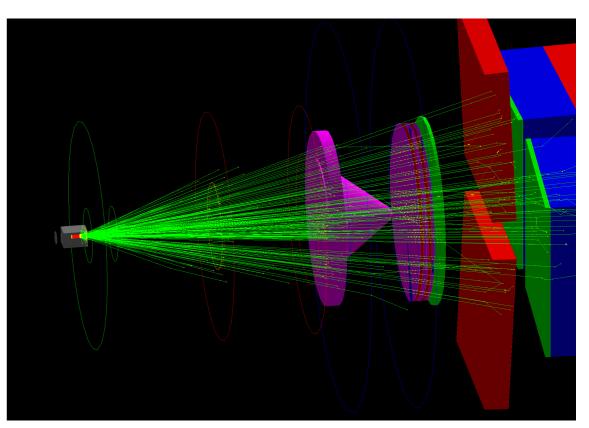




Introduction

- Electromagnetic (EM) physics overview
- Gamma processes
- Charged particles processes
- Production Threshold
- ♦ EM Physics Constructors
- User Interfaces to EM physics





Medical Linac



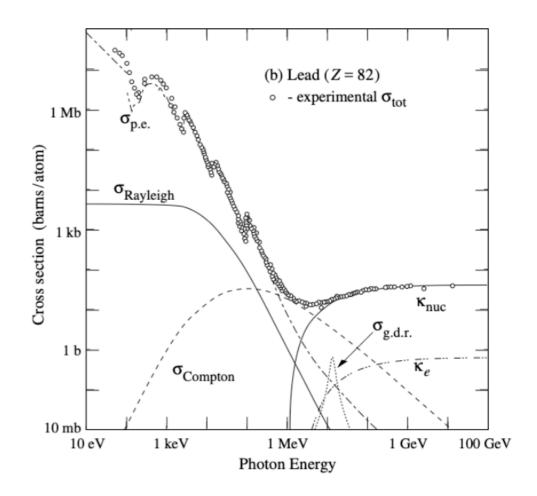
EM Overview

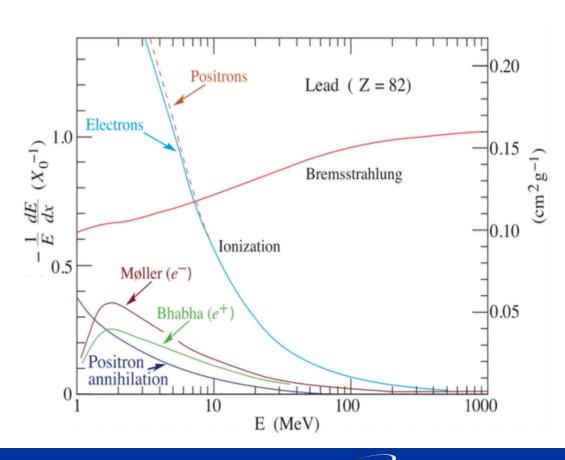
♦ Gamma processes

- γ conversion into e+e- pair
- Compton scattering
- Photoelectric effect
- Rayleigh scattering
- Gamma-nuclear interaction in hadronic library

Charged particles processes

- Ionization
- Coulomb scattering
- Bremsstrahlung
- Production of e+e- pair
- Positron annihilation
- Nuclear interaction in hadronic library





EM Libraries

Located in \$G4SOURCE/processes/electromagnetic

Standard

- γ, e up to 100 TeV
- hadrons up to 100 TeV
- ions up to 100 TeV

♦ Muons

- up to 1 PeV
- energy loss propagator

★ X-rays

Cherenkov, transition, synchrotron

→ High-energy

- processes at high energy (E>10GeV), for example γ to μ+μ- pairs, e-e+ to π- and π+
- physics for exotic particles

♦ Polarisation

models/processes for polarized beam

♦ Low-energy

- Livermore library γ, e- from 10 eV up to 1 GeV
- Livermore library based polarized processes
- PENELOPE 2008 code rewrite γ, e- , e+ from 250 eV up to 6 GeV
- hadrons and ions up to 1 GeV
- atomic de-excitation (fluorescence + Auger)

♦ DNA

- Geant4 DNA modes and processes
- Micro-dosimetry models for radiobiology
- from 0.025 eV to 10 MeV
- many of them material specific (water)

♦ Adjoint

- sub-library for reverse Monte Carlo simulation from the detector of
- interest back to source of radiation

◆ Utils

general EM interfaces and helper classes



- ◆ Uniform, coherent design approach over the different EM sub-parts
 - Standard and low-energy EM models/processes can be combined

- ◆ Uniform, coherent design approach over the different EM sub-parts
 - Standard and low-energy EM models/processes can be combined
- ◆ A physical interaction or process is described by a process class
 - For example: G4ComptonScattering
 - Assigned to particle types in the Physics List (G4ComptonScattering is assigned to photon)

- ◆ Uniform, coherent design approach over the different EM sub-parts
 - Standard and low-energy EM models/processes can be combined
- A physical interaction or process is described by a process class
 - For example: G4ComptonScattering
 - Assigned to particle types in the Physics List (G4ComptonScattering is assigned to photon)
- Three EM process interfaces to describe 3 set of interactions with different characteristics. All classes derived from these 3.
 - **G4VEmProcess** for discrete EM processes (e.g. Compton scattering)
 - G4VEnergyLossProcess for the continuous-discrete ionization and bremsstrahlung photon emission
 - **G4VMultipleScattering** for the Condensed History description of the multiple Coulomb scattering (along a given step)



- ◆ Uniform, coherent design approach over the different EM sub-parts
 - Standard and low-energy EM models/processes can be combined
- A physical interaction or process is described by a process class
 - For example: G4ComptonScattering
 - Assigned to particle types in the Physics List (G4ComptonScattering is assigned to photon)
- **♦** Three EM process interfaces to describe 3 set of interactions with different characteristics. All classes derived from these 3.
 - G4VEmProcess for discrete EM processes (e.g. Compton scattering)
 - ❖ G4VEnergyLossProcess for the continuous-discrete ionization and bremsstrahlung photon emission
 - **G4VMultipleScattering** for the Condensed History description of the multiple Coulomb scattering (along a given step)
- ◆ A EM process can be simulated according to several models
 - * Each model is described by a class that inherits from G4VEmModel base class
 - Naming convention: G4ModelNameProcessNameModel (e.g. G4KleinNishinaComptonModel describes Compton scattering of photons described by the Klein-Nishina differential cross section)
 - Models can be assigned to certain energy ranges and G4Regions

- Uniform, coherent design approach over the different EM sub-parts
 - Standard and low-energy EM models/processes can be combined
- A physical interaction or process is described by a process class
 - For example: G4ComptonScattering
 - Assigned to particle types in the Physics List (G4ComptonScattering is assigned to photon)
- **♦** Three EM process interfaces to describe 3 set of interactions with different characteristics. All classes derived from these 3.
 - G4VEmProcess for discrete EM processes (e.g. Compton scattering)
 - ❖ G4VEnergyLossProcess for the continuous-discrete ionization and bremsstrahlung photon emission
 - * G4VMultipleScattering for the Condensed History description of the multiple Coulomb scattering (along a given step)
- ◆ A EM process can be simulated according to several models
 - * Each model is described by a class that inherits from G4VEmModel base class
 - Naming convention: G4ModelNameProcessNameModel (e.g. G4KleinNishinaComptonModel describes Compton scattering of photons described by the Klein-Nishina differential cross section)
 - Models can be assigned to certain energy ranges and G4Regions
- Model classes provide the computation of:
 - Computation of interaction cross section (and stopping power if any)
 - Computation/generation of the interaction final state (post-interaction kinematics, secondary production, etc.)



Registering electronss in Standard EM

```
msc: for e- SubType= 10
            M models for the G4Region DefaultRegionForTheWorld ======
           UrbanMsc: Emin= 0 eV Emax= 100 TeV Nbins=240 100 eV - 100 TeV
         StepLim=DistanceToBoundary Rfact=0.04 Gfact=2.5 Sfact=0.6 DispFlag:1 Skin=1 Llim=1 mm
eIoni: for e- XStype:3 SubType=2
            range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 1
     StepFunction=(0.2, 0.1 mm), integ: 3, fluct: 1, linLossLim= 0.01
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
       MollerBhabha: Emin= 0 eV Emax= 100 TeV deltaVI
eBrem: for e- XStype:4 SubType=3
           and range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 1
     LPM flag: 1 for E > 1 GeV, VertexHighEnergyTh(GeV)= 100000
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
            eBremSB : Emin= 0 eV Emax=
                                            1 GeV AngularGen2BS
           eBremLPM : Emin= 1 GeV Emax= 100 TeV AngularGen2BS
ePairProd: for e- XStype:1 SubType=4
              range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 0
     Sampling table 25x1001; from 0.1 GeV to 100 TeV
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
          ePairProd : Emin= 0 eV Emax= 100 TeV ModifiedMephi
```

Registering electronss in Standard EM

```
msc: for e- SubType= 10
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
                              0 eV Emax= 100 TeV Nbins=240 100 eV - 100 TeV
           UrbanMsc : Emin=
         StepLim=DistanceToBoundary Rfact=0.04 Gfact=2.5 Sfact=0.6 DispFlaq:1 Skin=1 Llim=1 mm
eIoni: for e- XStype:3 SubType=2
     dE/dx and range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 1
     StepFunction=(0.2, 0.1 mm), integ: 3, fluct: 1, linLossLim= 0.01
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
       MollerBhabha: Emin= 0 eV Emax= 100 TeV deltaVI
eBrem: for e- XStype:4 SubType=3
     dE/dx and range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 1
     LPM flag: 1 for E > 1 GeV, VertexHighEnergyTh(GeV)= 100000
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
            eBremSB : Emin= 0 eV Emax=
                                            1 GeV AngularGen2BS
           eBremLPM : Emin= 1 GeV Emax= 100 TeV AngularGen2BS
ePairProd: for e- XStype:1 SubType=4
     dE/dx and range tables from 10 eV to 100 TeV in 260 bins
     Lambda tables from threshold to 100 TeV, 20 bins/decade, spline: 0
     Sampling table 25x1001; from 0.1 GeV to 100 TeV
     ==== EM models for the G4Region DefaultRegionForTheWorld =====
          ePairProd : Emin= 0 eV Emax= 100 TeV ModifiedMephi
```

Gamma Processes

Main processes (low to high energy)

- Photoelectric effect
- Rayleigh scattering should not be neglected if an accurate dosimetry simulation is needed
- Compton scattering
- Gamma absorption by Nuclei (giant dipole resonance)
- y conversion into e+e- pair

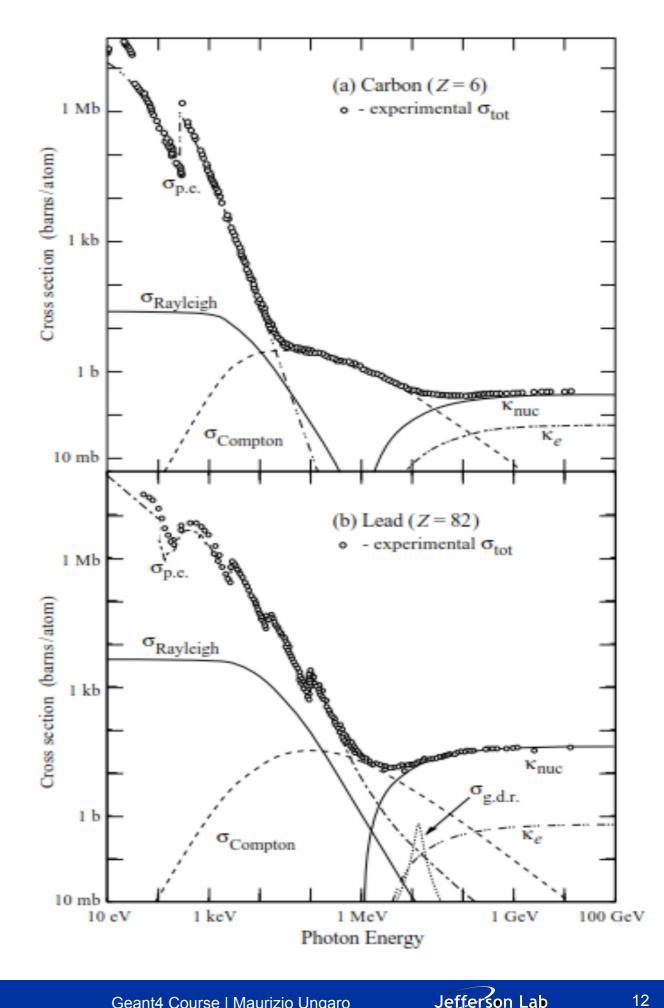
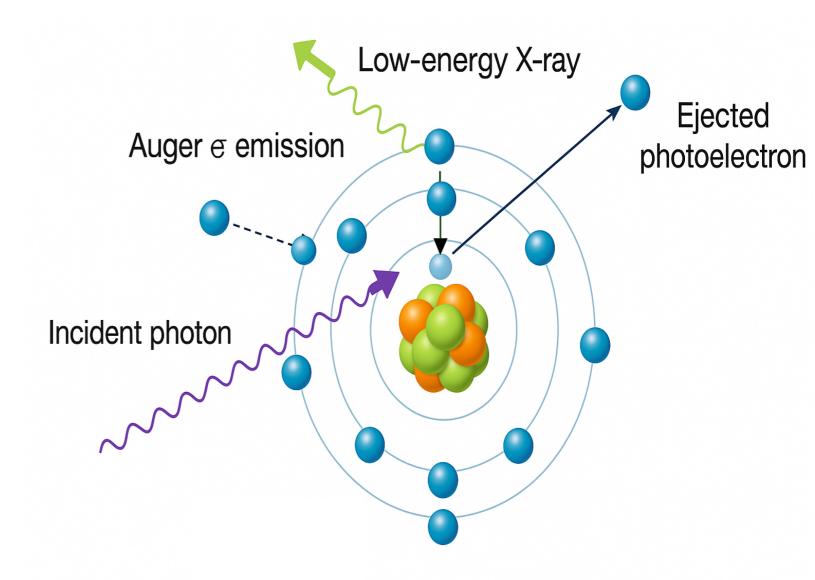


Photo-electric absorption and atomic de-excitation

- ♦ Photo-electric absorption leaves the atom in an excited state
- Vacancy in the ionized shell
- Decay through a cascade of radiated and non radiated transitions
- Emission of X-rays and other electrons



Atomic de-excitation

- Atomic de-excitation is initiated by other EM physics interactions
 - Photoelectric effect, ionization (by e- or ions), Compton scattering, ... •
 - These interactions leave the target atom in an excited state

Atomic de-excitation

- ◆ Atomic de-excitation is **initiated** by other EM physics interactions
 - Photoelectric effect, ionization (by e- or ions), Compton scattering, ...
 - These interactions leave the target atom in an excited state
- The EADL (Evaluated Atomic Data Library) contains transition probabilities: Decay through a cascade of radiated and non radiated transitions
 - Radiative transition characteristic X-ray emission (fluoressence photon emission)
 - Auger e- emission: initial and final vacancies are in different shells
 - Coster-Kronig e- emission: initial and final vacancies are in the same shells

Atomic de-excitation

- Atomic de-excitation is initiated by other EM physics interactions
 - Photoelectric effect, ionization (by e- or ions), Compton scattering, ...
 - These interactions leave the target atom in an excited state
- The EADL (Evaluated Atomic Data Library) contains transition probabilities: Decay through a cascade of radiated and non radiated transitions
 - Radiative transition characteristic X-ray emission (fluoressence photon emission)
 - Auger e- emission: initial and final vacancies are in different shells
 - Coster-Kronig e- emission: initial and final vacancies are in the same shells
- De-excitation has common interface so is compatible with both the standard and the low-energy EM physics categories
 - It can be enabled and controlled by UI command (before initialization)

```
/process/em/fluo true
/process/em/auger true
/process/em/pixe true
/run/initialize
```

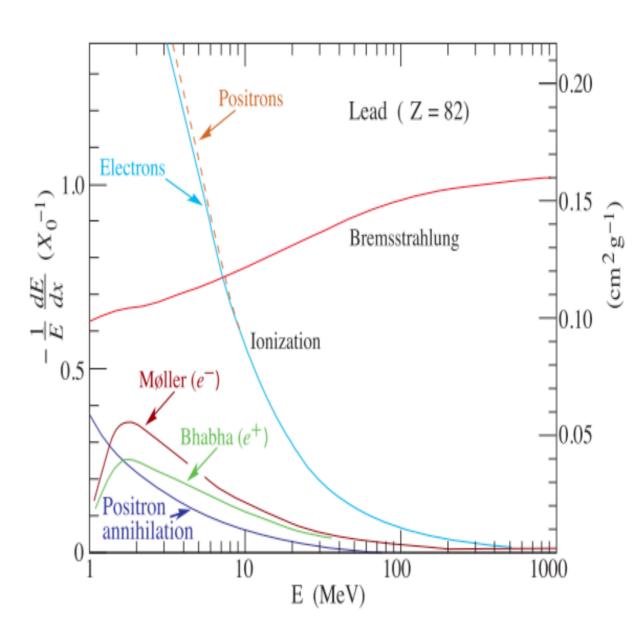
The fluorescence transition is active by default in some EM physics constructor while others (Auger, PIXE) not



Charged particles processes

Charged particles processes (low to high energy)

- Positron annihilation
- Ionization dominates
- Bremsstrahlung
- Coulomb scattering
- Production of e+e- pair



Difference between electrons and positrons is significant for low energy but practically negligible above critical energy

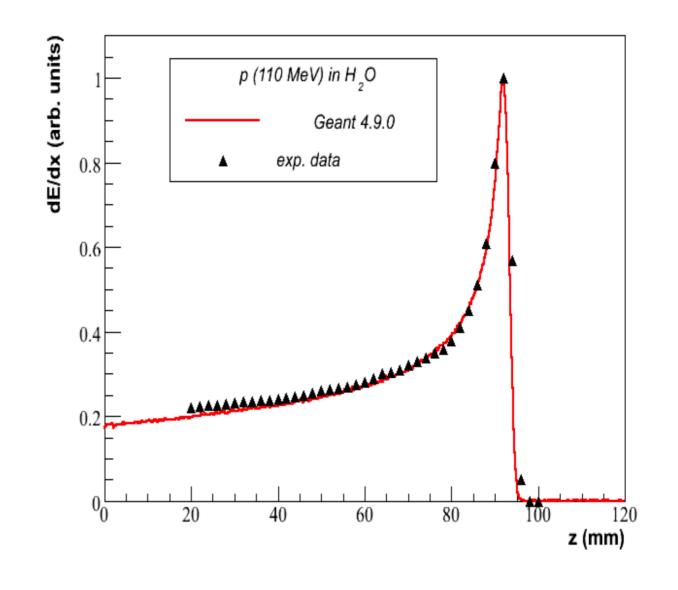
Charged particles: simulation of g4step

- ◆ Values of mean dE/dx, range, cross section of δ-electron production, and bremsstrahlung are pre-computed at initialization stage of Geant4 and are stored in a G4PhysicsTable
- At run time, for each simulation g4step
 - 1. a spline interpolation of tables is used to get the mean energy loss
 - 2. a call to the the general interface to a fluctuation model is G4VEmFluctuationModel
 - 3. a sampling of the energy loss fluctuation is performed
- the cross sections of δ-electron production and bremsstrahlung are used to sample production above the threshold T_{CUT} at PostStep
- ◆ If atomic de-excitation is active, then fluorescence and Auger electron production is sampled AlongStep and PostStep

1: Hadrons and ion ionization: get mean energy loss

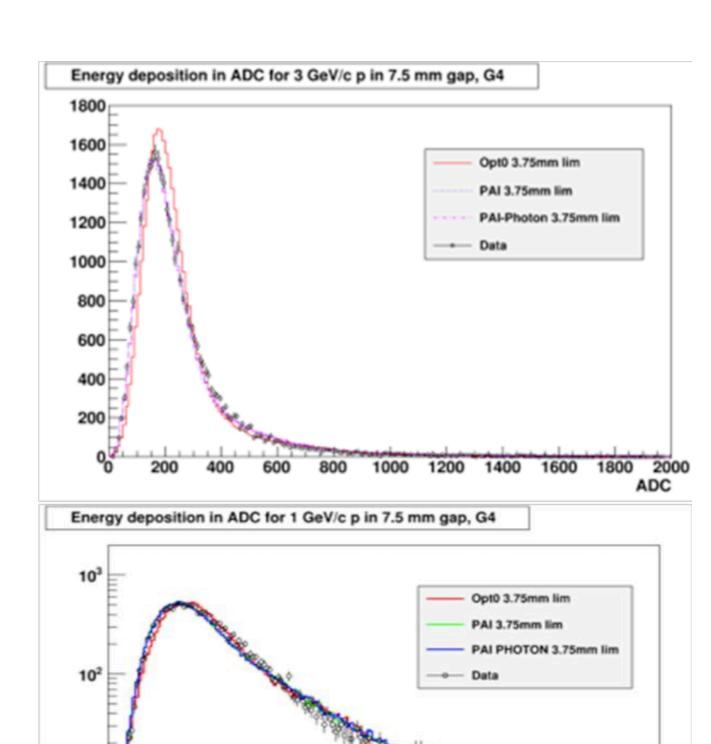
$$-\frac{dE}{dx} = 4\pi N_e r_0^2 \frac{z^2}{\beta^2} \left[\ln \frac{2m_e c^2 \beta^2 \gamma^2}{I} - \frac{\beta^2}{2} \left(1 - \frac{T_c}{T_{\text{max}}} \right) - \frac{C}{Z} + \frac{G - \delta - F}{2} + zL_1 + z^2 L_2 \right]$$

- ♦ C: shell correction
- → G: Mott correction
- δ density correction
- ♦ F: finite size correction
- ◆ L₁: Barkas correction
- ◆ L₂: Block correction
- Nuclear stopping
- Ion effective range
- Scaling for heavy particles / ions



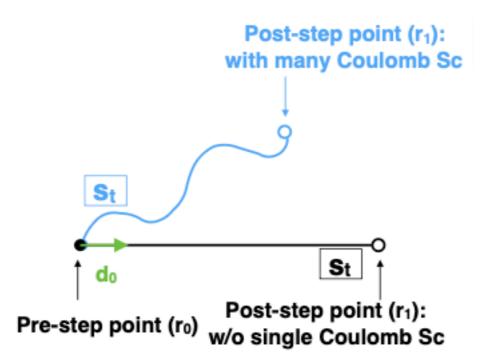
2, 3: Fluctuations models

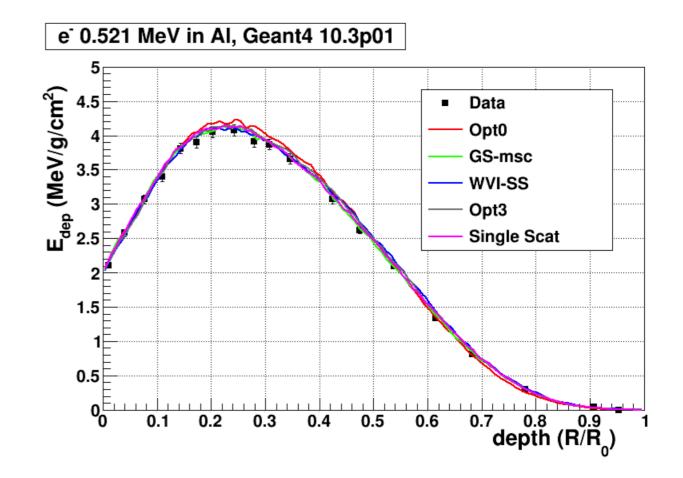
- Urban model based on a simple model of particle-atom interaction
 - Atoms are assumed to have only two energy levels: E₁ and E₂
 - Particle-atom interaction can be:
 - an excitation of the atom with energy loss $E = E_1 - E_2$
 - an ionization with energy loss distribution $g(E) \approx 1/E^2$
- PAI model uses photo absorption cross section data
 - Relativistic model
 - Energy transfers are sampled with production of secondary e- or y
 - Very slow model
 - Takes into account each ionization collision

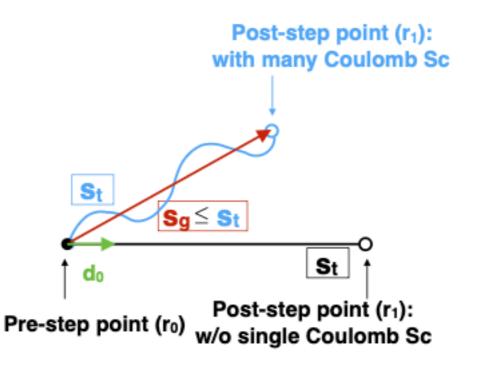


Electron/positron Multiple Scattering Models

- Coulomb scattering: elastic scattering of charged particles on the atomic potential
- Event-by-event modeling of elastic scattering is feasible only if the mean number of interactions per track is below few hundred
- this limits the applicability of the detailed simulation model only for electrons with relatively low kinetic energies (up to Ekin ~100 keV) or thin targets
- **MSC model:** give the final position and direction of the particle while try to minimize the possible errors due to geometrical constraints



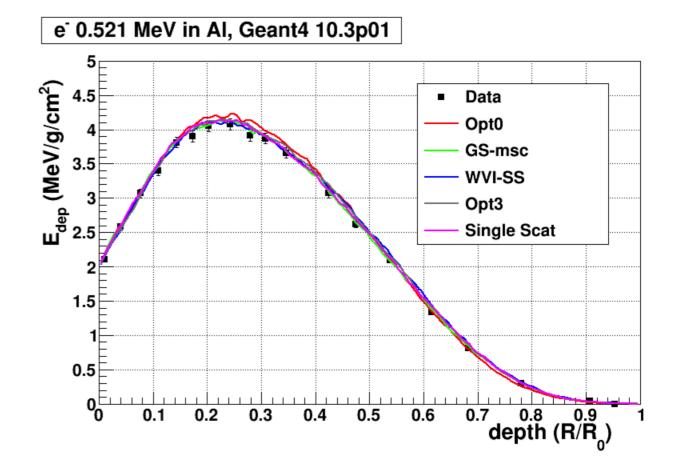






Electron/positron Multiple Scattering Models

- MSC model: give the final position and direction of the particle while try to minimize the possible errors due to geometrical constraints
- Can be controlled with UI command (in increasing accuracy and simulation time)



```
/process/msc/StepLimit UseSafety
/process/msc/StepLimit UseDistanceToBoundary
/process/msc/StepLimit UseSafetyPlus
```

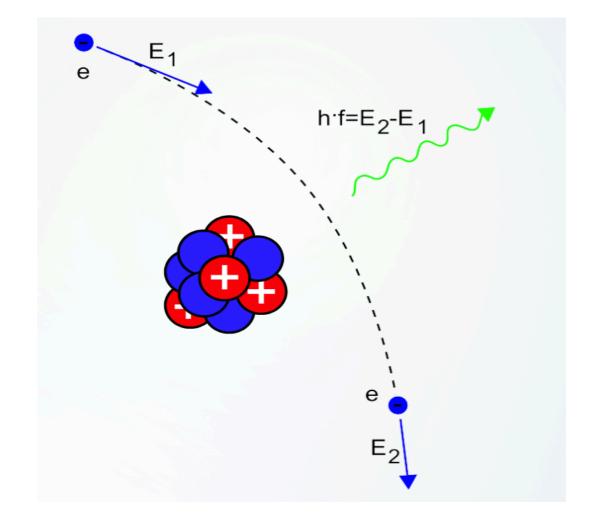
these are for e-/e+ but different UI command available for muons and hadrons

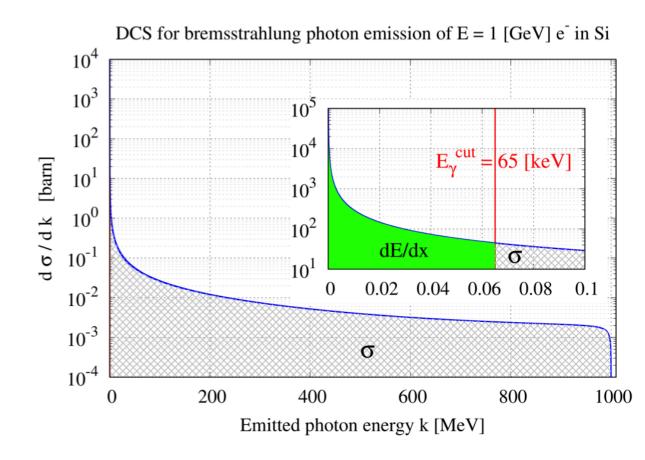


For Bremsstrahlung

- Low energy photons (k) are emitted with high rate:
 DCS ~ 1/k
- The generation and tracking of all these low energy photons would not be feasible (CPU time)
- Low energy photons has a very small absorption length
- If the detector spacial resolution is worse than this length then the following scenario are exactly the same in terms of final result of a simulation:
 - A. Generating and tracking these low energy photons till all their energy will be deposited
 - B. Depositing their corresponding energy at the creation point (at a trajectory point)

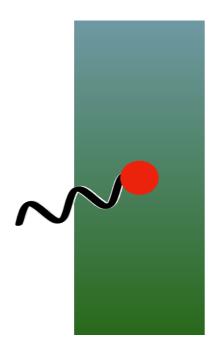
B is equivalent to A but much faster.
We can control these situations with a production threshold cut.





Energy vs Length

- It may seem more intuitive at first for users to provide a threshold in ENERGY
- But the same energy will translate to different lengths (absorption length, range) in different materials: a 10 keV gamma has very different absorption length in Pb or in Ar gas





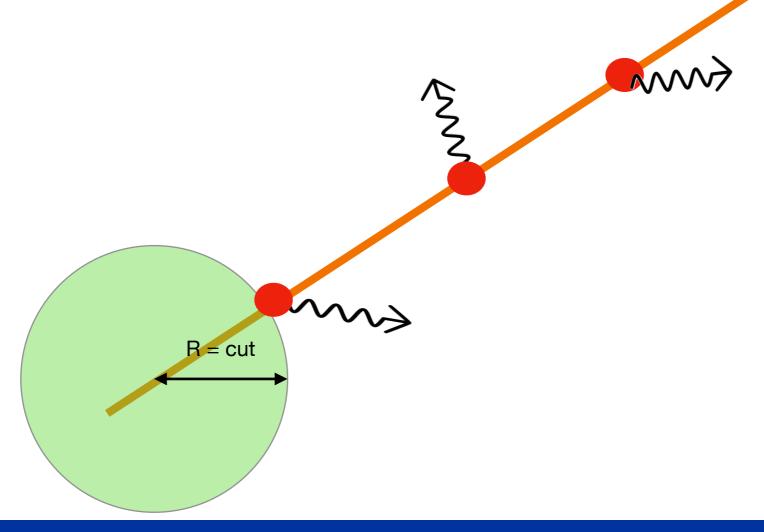
- Moreover, the same energy will translate to different lengths depending on the particle type (gamma => absorption length; e-/e+ => range) even in the same material: range of a 10 keV e- in Si is few micron while the absorption length of a 10 keV gamma in Si is few cm
- If we wanted to use energy threshold, we would need values per material and per particle!

A cut in length is more intuitive (after you think about it a bit) and directly related to detector dimensions

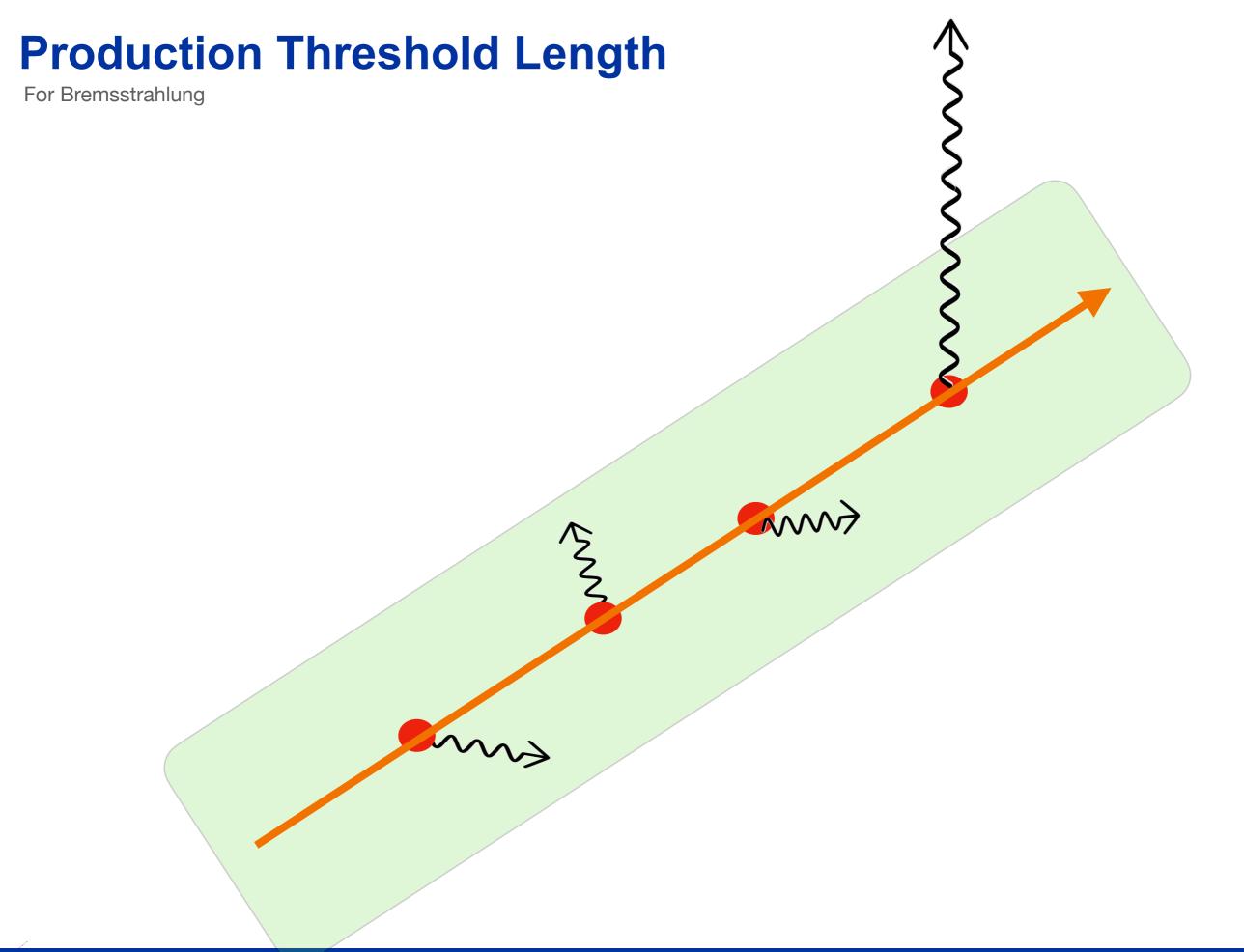
Production Threshold Length

For Bremsstrahlung

Here the photon length is how much it travels in that material ~ its energy







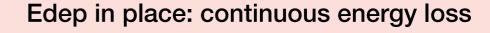
Production Threshold Length

For Bremsstrahlung

$$\sigma(E, E_{\gamma}^{\text{cut}}, Z) = \int_{E_{\gamma}^{\text{cut}}}^{E} \frac{d\sigma}{dk}(E, Z) dk$$

Discrete event: y production

The emission rate is determined by the corresponding restricted cross section(σ)



$$\frac{\mathrm{d}E}{\mathrm{d}x}(E, E_{\gamma}^{\mathrm{cut}}, Z) = \mathcal{N} \int_{0}^{E_{\gamma}^{\mathrm{cut}}} k \frac{\mathrm{d}\sigma}{\mathrm{d}k}(E, Z) \mathrm{d}k$$



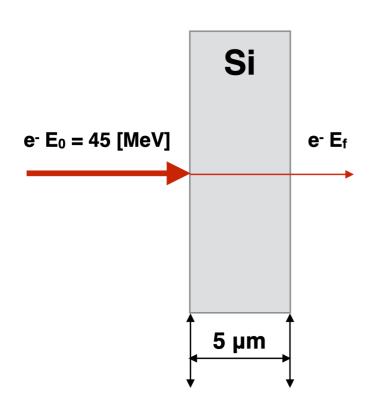
- → The corresponding Edep energy (that would have been taken away from the primary) is accounted as CONTINUOUS energy loss of the primary particle along its trajectory
- **♦** Same applies to ionization with the difference:
 - * secondary gamma → secondary e- production threshold
 - absorption length → range
- ◆ Range and absorption production length is internally translated to energies at initialization, taking care of material and particle dependency
- → Production threshold defined for gamma, e-, e+ and proton secondary particle:
 - gamma production threshold is used in bremsstrahlung while the e- in ionization
 - e+ production threshold might be used in case of e-/e+ pair production
 - proton production threshold is used as a kinetic energy threshold for nuclear recoil in case of elastic scattering of all hadrons and ions
- ◆ Production threshold are not mandatory, but many physics simulation would not be feasible w/o them

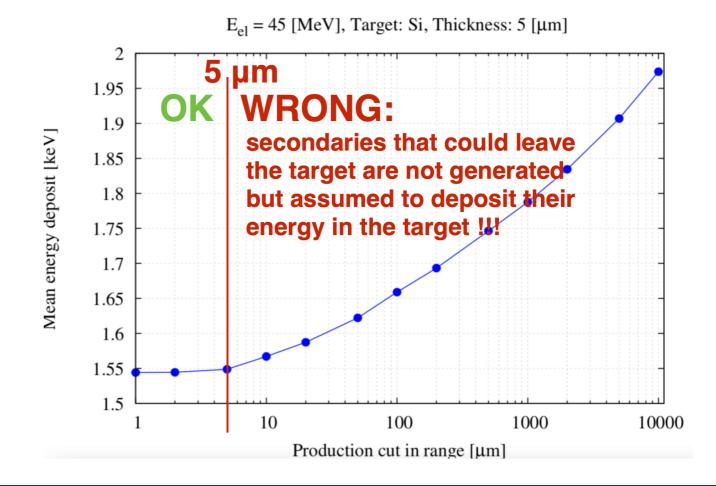
- ◆ User needs to provide them in length (with a default value of 0.7 mm for the reference physics lists
- UI commands to define cuts:

```
/run/setCut 0.1 mm
/run/setCutForAGivenParticle e- 0.01 mm
/run/setCutForRegion GasDetector 0.001 mm
/cuts/setLowEdge 500 eV
```

- User needs to provide them in length (with a default value of 0.7 mm for the reference physics lists
- UI commands to define cuts:

```
/run/setCut 0.1 mm
/run/setCutForAGivenParticle e- 0.01 mm
/run/setCutForRegion GasDetector 0.001 mm
/cuts/setLowEdge 500 eV
```





Production Threshold per detector region

- Different parts of a complex detector might require modeling with different level of details and have different spacial resolution
- → Different detector G4Regions can be defined and a set of G4LogicalVolumes can be associated to such regions
- ◆ Different secondary production threshold values (as well as G4UserLimits) can be assigned to different detector region
- ◆ In the DetectorConstruction::Construct() method (e.g. examples/ extended/ electromagnetic/TestEm9)

```
// Production threshold for "Our-Region"
auto* cuts = new G4ProductionCuts;
cuts->SetProductionCut(0.5*mm); // same cuts for gamma, proton, e- and e+
cuts->SetProductionCut(0.2*mm,G4ProductionCuts::GetIndex("e-"));

// Create region and assign cuts
auto* region = new G4Region("Our-Region");
region->SetProductionCuts(cuts);

// Assign volume to region: all volumes will have these cuts
region->AddRootLogicalVolume(my_specific_logical_volume);
```

Production Threshold per detector region

- Different parts of a complex detector might require modeling with different level of details and have different spacial resolution
- ◆ Different detector G4Regions can be defined and a set of G4LogicalVolumes can be associated to such regions
- ◆ Different secondary production threshold values (as well as G4UserLimits) can be assigned to different detector region
- ♦ In the DetectorConstruction::Construct() method (e.g. examples/ extended/ electromagnetic/TestEm9)

```
used in the geometry : Yes
Index: 0
Material : Galactic
                 : gamma 700 um
                                                    e+ 700 um proton 700 um
Range cuts
                                      e- 700 um
 Energy thresholds: gamma 990 eV
                                         990 eV
                                                        990 eV proton 70 keV
Region(s) which use this couple :
   DefaultRegionForTheWorld
             used in the geometry: Yes
Index : 1
Material: G4_Pb
Range cuts
                  : gamma 700 um
                                                    e+ 700 um proton 700 um
                                      e- 700 um
Energy thresholds: gamma 94.5861 keV
                                          e- 1.00386 MeV
                                                            e+ 951.321 keV proton 70 ke
Region(s) which use this couple :
   DefaultRegionForTheWorld
Ir ex : 2
             used in the geometry : Yes
Material : G4_lAr
                : gamma 100 um
Range cuts
                                                    e+ 100 um proton 100 um
                                      e- 100 um
Energy thresholds: gamma 2.00482 keV
                                          e- 82.9692 keV
                                                            e+ 81.8616 keV proton 10 keV
 Region(s) which use this couple :
   Our-Region
```

Standard EM Physics Constructors

List of particles for which EM physics processes are defined

Photon, leptons, meson and baryons:

$$\gamma$$
, e^{\pm} , μ^{\pm} , π^{\pm} , K^{\pm} , p , Σ^{\pm} , Ξ^{-} , Ω^{-} , anti(Σ^{\pm} , Ξ^{-} , Ω^{-})

✦ Heavy leptons & heavy mesons, charmed baryons:

$$T^{\pm}$$
, B^{\pm} , D^{\pm} , D_c^{\pm} , $Λ_c^{+}$, $Σ_c^{+}$, $Σ_c^{++}$, $Ξ_c^{++}$, anti($Λ_c^{+}$, $Σ_c^{+}$, $Σ_c^{++}$, $Ξ_c^{+}$)

◆ Light nuclei:

```
d, t, <sup>3</sup>He, <sup>4</sup>He, generic-ion, anti(d, t, <sup>3</sup>He, <sup>4</sup>He)
```

◆ 12 light hyper- and anti-hyper- nuclei

Standard EM Physics Constructors

- The modular Physics Lists (G4VModularPhysicsList) allows to build up a complete physics list from "physics modules"
- ◆ A given "physics module" handles a well defined category of physics (e.g.EM physics, decay physics, etc.) as a sub-set of a complete physics list
- ◆ G4VPhysicsConstructor is the Geant4 interface to describe such subsets of physics
- Several EM physics constructors, i.e. pre-defined EM sub-set of a complete physics list, are available in Geant4
- Each particle has its own G4ProcessManager that maintains the list of assigned processes (e.g., ionization, multiple scattering, decay)



Standard EM Physics Constructors

- The modular Physics Lists (G4VModularPhysicsList) allows to build up a complete physics list from "physics modules"
- ◆ A given "physics module" handles a well defined category of physics (e.g.EM physics, decay physics, etc.) as a sub-set of a complete physics list
- ◆ G4VPhysicsConstructor is the Geant4 interface to describe such subsets of physics
- ◆ Several EM physics constructors, i.e. pre-defined EM sub-set of a complete physics list, are available in Geant4
- ◆ Each particle has its own G4ProcessManager that maintains the list of assigned processes (e.g., ionization, multiple scattering, decay)

```
auto particleIterator = GetParticleIterator();
particleIterator->reset();
while( (*particleIterator)() ){
   G4ParticleDefinition* particle = particleIterator->value();
   auto* pmanager = particle->GetProcessManager();
   // Attach processes here
   pmanager->AddProcess(new G4eIonisation, ordInActive, ordAlongStep, ordPostStep);
}
```

Standard EM Physics Constructors for HEP

- SAME: Description of Coulomb scattering
 - e±: Urban MSC model below 100 [MeV] and the Wentzel WVI + Single scattering (mixed simulation) model above 100 [MeV]
 - muon and hadrons: Wentzel WVI + Single scattering (mixed simulation) model
 - ions: Urban MSC model
- Different MSC stepping algorithms and/or parameters: speed v.s. accuracy

Constructor	Components	Comment
EmStandardPhysics	Defaults (FTFP_BERT)	for ATLAS and other HEP simulation applications
G4EmStandardPhysics_option1	Fast: due to simpler MSC step limitation, cuts used by photon processes (FTFP_BERT_ EMV)	similar to one used by CMS; good for crystals but not good for sampling calorimeters (i.e. with more detailed geometry)
G4EmStandardPhysics_option2	Experimental: similar to option1 with updated photoelectric model but nodisplacement in MSC (FTFP_BERT_ EMX)	similar to one used by LHCb

Standard EM Physics Constructors: more precise

- The primary goal is more the physics accuracy over the speed
- Combination of standard and low-energy EM models for more accurate physics description
- More accurate models for e[±] MSC (Goudsmit-Saunderson(GS)) and/or more accurate stepping algorithms (compared to HEP)
- Stronger continuous step limitation due to ionization (as others given per particle groups)
- Recommended for more accuracy sensitive applications: medical (hadron/ion therapy), space

Constructor	Components	Comment
G4EmStandardPhysics_option3	Urban MSC model for all charged particles (FTFP_BERT_ EMY)	proton/ion therapy
G4EmStandardPhysics_option4	most accurate combination of models (particle type and energy) GS MSC (FTFP_BERT_EMZ)	The most accurate EM physics
G4EmLivermorePhysics	Livermore gamma and e- ionisation models GS MSC (FTFP_BERT_ LIV)	Recommended for cross-checks of option4
G4EmPenelopePhysics	Penelope gamma and e± ionisation and bremsstrahlung models GS MSC (FTFP_BERT_ PEN)	Recommended for cross-checks of option4

Extra experimental constructors are available in Geant4 examples



EM parameters of any EM physics list may be accessed or modified at initialization of Geant4 using:

UI commands

```
/process/eLoss/verbose 0
/process/eLoss/maxKinEnergyCSDA 100 TeV

/process/em/deexcitationIgnoreCut true
/process/eLoss/UseAngularGenerator true
/process/em/lowestElectronEnergy 50 eV
/process/em/lowestMuHadEnergy 100 keV
```

/process/em/printParameters

EM parameters of any EM physics list may be accessed or modified at initialization of Geant4 using:

◆ C++ interface to the G4EmParameter (EM options) class

PhysListEmStandard.cc in extended/electromagnetic/TestEm0

PhysycsList.cc in extended/electromagnetic/TestEm0

```
void PhysicsList::AddPhysicsList(const G4String& name) {
    G4EmParameters::Instance()->SetBuildCSDARange(true);
    G4EmParameters::Instance()->SetGeneralProcessActive(false);
}
```



EM parameters of any EM physics list may be accessed or modified at initialization of Geant4 using:

◆ C++ interface to the G4EmCalculator (access to cross sections and stopping powers) class

RunAction.cc in extended/electromagnetic/TestEm0

```
void RunAction::CriticalEnergy()
   // compute e- critical energy (Rossi definition) and Moliere radius.
   // Review of Particle Physics - Eur. Phys. J. C3 (1998) page 147
   G4EmCalculator emCal;
   const G4Material* material = fDetector->GetMaterial();
   const G4double radl = material->GetRadlen();
   G4double ekin = 5 * MeV;
   G4double deioni:
   G4double err = 1., errmax = 0.001;
   G4int iter = 0, itermax = 10;
   while (err > errmax && iter < itermax) {</pre>
       iter++;
       deioni = radl * emCal.ComputeDEDX(ekin, G4Electron::Electron(), "eIoni", material);
       err = std::abs(deioni - ekin) / ekin;
       ekin = deioni;
}
```

EM parameters of any EM physics list may be accessed or modified at initialization of Geant4 using:

- → G4EmCalculator: easy access to cross sections and stopping powers (TestEm0)
- ◆ G4EmParameters: EM options alternative to UI commands
- ◆ G4EmSaturation: Birks effect (saturation of response of sensitive detectors)
- ◆ G4ElectronIonPair: sampling of ionization clusters in gaseous or silicon detectors
- ◆ G4EmConfigurator: add models per energy range and geometry region
- ◆ G4NIELCalculator: Helper class allowing computation of NIEL at a step, which should be added in user stepping actions or sensitive detector (**TestEm1**)

Extract EM PHYSICS

EM parameters of any EM physics list may be accessed or modified at initialization of Geant4 using:

- ◆ Use C++ interface to the G4EmCalculator (after physics list is initialized)
- ◆ Example for retrieving the total cross section of a process with name procName, for particle and material matName

```
#include "G4EmCalculator.hh"

{
    G4EmCalculator emCalculator;
    G4Material* material =
    G4NistManager::Instance()->FindOrBuildMaterial(matName);
    G4double density = material->GetDensity();
    G4double massSigma = emCalculator.ComputeCrossSectionPerVolume
    (energy, particle, procName, material)/density;
    G4cout << G4BestUnit(massSigma, "Surface/Mass") << G4endl;
}</pre>
```

Summary

- Overview of the main EM physics and classes in Geant4.
- There is a lot more physics in Geant4 (DNA project, etc, see also EM 2)
- Choosing the correct EM physics list while optimizing the simulation efficiency is the one of the most important issue you will face.
- We suggest starting with the standard list and if accuracy is extremely important to you, compare with option 4. This will give you an idea of your needs.